



### **DUAL N-CHANNEL ENHANCEMENT MODE MOSFET**

### **Product Summary**

BV <sub>DSS</sub>	Rds(ON) Max	I <sub>D</sub> Max @T <sub>A</sub> = +25°C
	1.5Ω @ V <sub>GS</sub> = 4.5V	0.43A
30V	2.0Ω @ V <sub>GS</sub> = 2.5V	0.37A
300	3.0Ω @ V <sub>GS</sub> = 1.8V	0.3A
	4.5Ω @ V <sub>GS</sub> = 1.5V	0.25A

### **Description**

This new generation MOSFET is designed to minimize the on-state resistance (R<sub>DS(ON)</sub>) yet maintain superior switching performance, making it ideal for high-efficiency power-management applications.

## **Applications**

- Battery operated systems and solid-state relays
- Drivers, relays, solenoids, lamps, hammers, displays, memories, transistors
- Power-supply converter circuits

### **Features and Benefits**

- Low On-Resistance
- Low Gate Threshold Voltage
- Low Input Capacitance
- Fast Switching Speed
- Low Input/Output Leakage
- Ultra-Small Surface-Mount Package
- ESD Protected
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- The DMN31D5UDWQ is suitable for automotive applications requiring specific change control; this part is AEC-Q101 qualified, PPAP capable, and manufactured in IATF 16949 certified facilities.

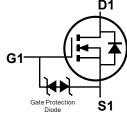
https://www.diodes.com/quality/product-definitions/

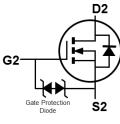
#### **Mechanical Data**

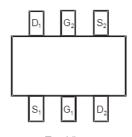
- Package: SOT363
- Package Material: Molded Plastic, "Green" Molding Compound.
   UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Matte Tin Finish Annealed over Alloy 42 Leadframe (Lead Free Plating). Solderable per MIL-STD-202, Method 208@3
- Terminal Connections: See Diagram
- Weight: 0.006 grams (Approximate)











Top View

Q1 N-Channel

Q2 N-Channel

Top View Pin-out

### Ordering Information (Note 4)

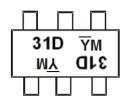
Orderable Part Number	Dockers	Packing		
Orderable Part Number	Package	Qty.	Carrier	
DMN31D5UDWQ-7	SOT363	3,000	Tape & Reel	
DMN31D5UDWQ-13	SOT363	10,000	Tape & Reel	

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.



## **Marking Information**



31D = Product Type Marking Code  $\underline{Y}M$  = Date Code Marking  $\overline{Y}$  = Year (ex: M = 2025) M = Month (ex: 9 = September)

Date Code Key

Year	2025	2026	2027	2028	2029	2030	2031	2032	2033	2034	2035	2036
Code	М	N	Р	R	S	T	U	V	W	Х	Υ	Z
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec

## **Maximum Ratings** (@TA = +25°C, unless otherwise specified.)

Characteri	Symbol	Value	Unit		
Drain-Source Voltage	V <sub>DSS</sub>	30	V		
Gate-Source Voltage	Vgss	±12	V		
Continuous Drain Current (Note 5) V <sub>GS</sub> = 4.5V	Steady State	T <sub>A</sub> = +25°C T <sub>A</sub> = +70°C	I <sub>D</sub>	0.43 0.28	А
Maximum Continuous Body Diode Forward Curre	Is	0.37	Α		
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1	%)		Ірм	0.65	Α

## Thermal Characteristics (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Total Power Dissipation (Note 6)	T <sub>A</sub> = +25°C	PD	0.33	W
Thermal Resistance, Junction to Ambient (Note 6)	Steady State	Reja	380	°C/W
Total Power Dissipation (Note 5)	T <sub>A</sub> = +25°C	P <sub>D</sub>	0.43	W
Thermal Resistance, Junction to Ambient (Note 5)	Steady State	Reja	290	°C/W
Operating and Storage Temperature Range		TJ, TSTG	-55 to +150	°C

Notes:

<sup>5.</sup> Device mounted on FR-4 substrate PC board, 2oz copper, with 1inch square copper plate.6. Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.



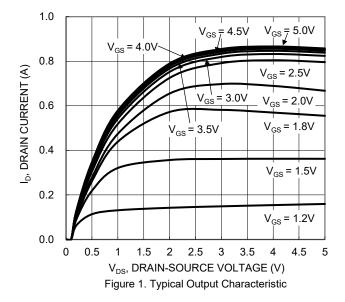
## Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

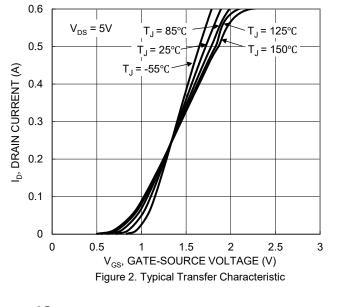
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 7)						
Drain-Source Breakdown Voltage	BVDSS	30	_	_	V	$V_{GS} = 0$ , $I_D = 250 \mu A$
Zero Gate Voltage Drain Current @Tc = +25°C	IDSS	_	_	100	nA	V <sub>DS</sub> = 24V, V <sub>GS</sub> = 0
Gate-Source Leakage	Igss	_	_	±10	μΑ	$V_{GS} = \pm 10V, V_{DS} = 0$
ON CHARACTERISTICS (Note 7)						
Gate Threshold Voltage	Vgs(TH)	0.5	_	0.9	V	$V_{DS} = V_{GS}$ , $I_D = 250\mu A$
			1.3	1.5		V <sub>GS</sub> = 4.5V, I <sub>D</sub> = 100mA
Static Drain-Source On-Resistance	Dagger		1.4	2.0	Ω	$V_{GS} = 2.5V, I_D = 50mA$
Static Dialii-Source Oil-Resistance	RDS(ON)	_	1.7	3.0	12	V <sub>GS</sub> = 1.8V, I <sub>D</sub> = 20mA
			1.9	4.5		V <sub>GS</sub> = 1.5V, I <sub>D</sub> = 10mA
Diode Forward Voltage (Note 7)	VsD	_	0.7	1.0	mV	V <sub>GS</sub> = 0, I <sub>S</sub> = 100mA
DYNAMIC CHARACTERISTICS (Note 8)						
Input Capacitance	C <sub>iss</sub>	_	15.4	_	pF	15)()(
Output Capacitance	Coss	_	8	_	pF	V <sub>DS</sub> = 15V, V <sub>GS</sub> = 0 - f = 1.0MHz
Reverse Transfer Capacitance	Crss	_	5	_	pF	1 = 1.0IVII IZ
Total Gate Charge	Qg	_	0.3	_	nC	4.5)/.)/
Gate-Source Charge	Qgs	_	0.05	_	nC	V <sub>GS</sub> = 4.5V, V <sub>DS</sub> = 15V
Gate-Drain Charge	Qgd	_	0.1	_	nC	71D - 20011IA
Turn-On Delay Time	t <sub>D(ON)</sub>	_	5.7	_	ns	
Turn-On Rise Time	t <sub>R</sub>	_	9.1	_	ns	V <sub>DD</sub> = 15V, V <sub>GS</sub> = 4.5V
Turn-Off Delay Time	t <sub>D(OFF)</sub>	_	146	_	ns	$R_G = 2\Omega$ , $I_D = 200 \text{mA}$
Turn-Off Fall Time	t <sub>F</sub>		48	_	ns	

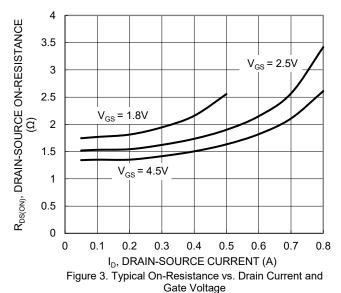
Notes:

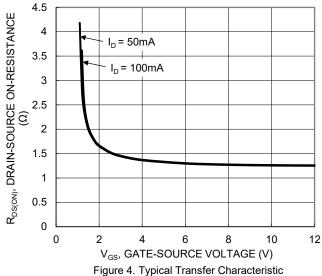
<sup>7.</sup> Short duration pulse test used to minimize self-heating effect. 8. Guaranteed by design. Not subject to production testing.

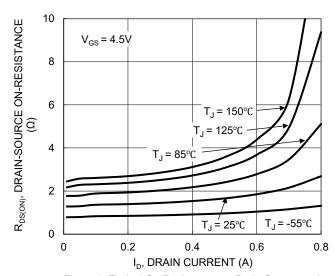












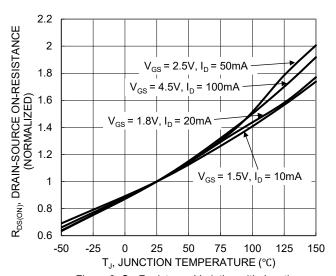


Figure 5. Typical On-Resistance vs. Drain Current and Junction Temperature

Figure 6. On-Resistance Variation with Junction Temperature





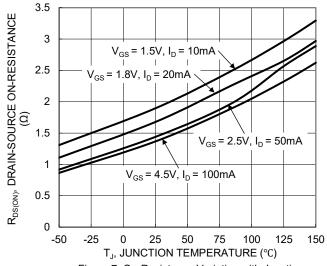
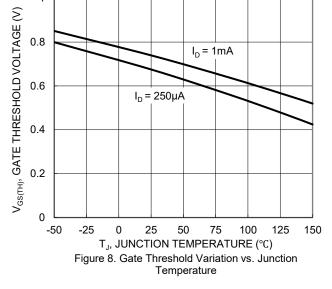


Figure 7. On-Resistance Variation with Junction Temperature



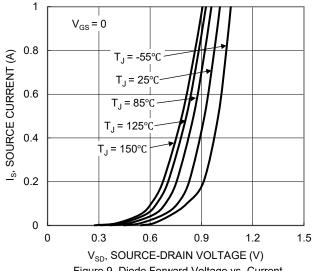
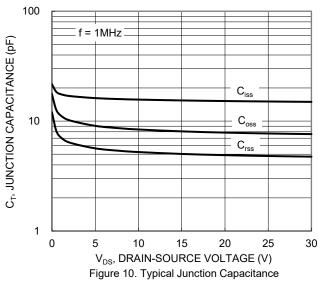
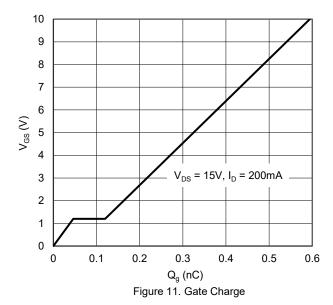
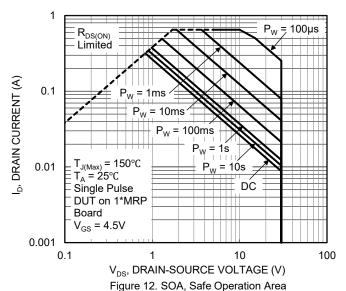


Figure 9. Diode Forward Voltage vs. Current









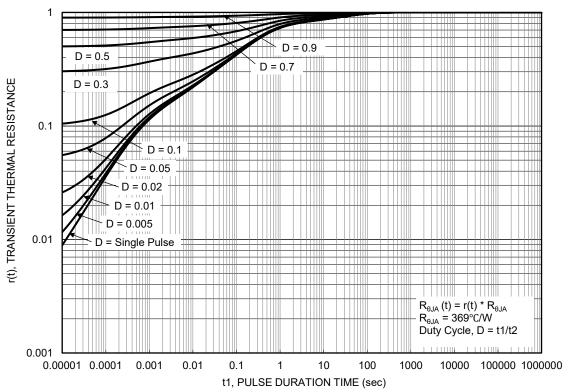


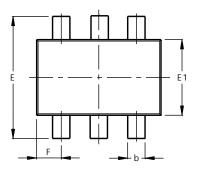
Figure 13. Transient Thermal Resistance

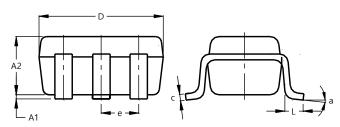


## **Package Outline Dimensions**

Please see http://www.diodes.com/package-outlines.html for the latest version.

#### **SOT363**



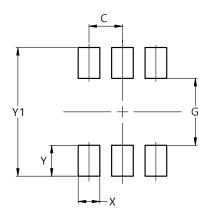


SOT363						
Dim	Min	Max	Тур			
A1	0.00	0.10	0.05			
A2	0.90	1.00	0.95			
b	0.10	0.30	0.25			
С	0.10	0.22	0.11			
D	1.80	2.20	2.15			
Е	2.00	2.20	2.10			
E1	1.15	1.35	1.30			
е	C	.650 E	SC			
F	0.40	0.45	0.425			
L	0.25	0.40	0.30			
а	0°	8°				
All I	Dimen	sions	in mm			

# **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.

#### **SOT363**



Dimensions	Value (in mm)
С	0.650
G	1.300
Х	0.420
Υ	0.600
V1	2 500



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